

isc N-Channel MOSFET Transistor

PHP33NQ20T

FEATURES

- Drain Current –I_D= 32.7A@ T_C=25 °C
- Drain Source Voltage-
 - : V_{DSS}=200V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)}$ =77m Ω (Max)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

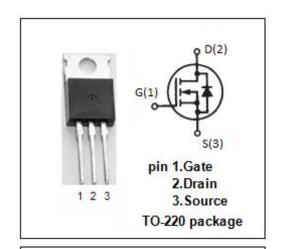
 Designed for use in switch mode power supplies and general purpose applications.

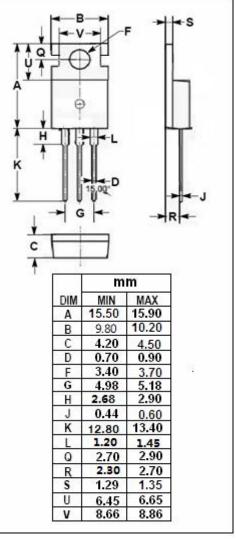
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|---|-------|------|
| V _{DSS} | Drain-Source Voltage | 200 | V |
| V _{GS} | Gate-Source Voltage-Continuous | ±20 | V |
| I _D | Drain Current-Continuous | 32.7 | А |
| I _{DM} | Drain Current-Single Pluse | 65.4 | А |
| P _D | Total Dissipation @T _C =25°C | | W |
| TJ | Max. Operating Junction Temperature -55~175 | | °C |
| T _{stg} | Storage Temperature -55~175 | | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|--------------------------------------|-----|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | | °C/W |





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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|----------------------|---------------------------------|--|-----|----------|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 0.25mA | 200 | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} = V _{GS} ; I _D = 1mA | 2.0 | 4.0 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D =15A | | 77 | mΩ |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} = ±20V;V _{DS} = 0 | | ±100 | nA |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =160V; V _{GS} = 0 V _{DS} =160V; V _{GS} = 0@T _J =175°C | | 1 500 | μА |
| V_{SD} | Forward On-Voltage | I _S = 25A; V _{GS} = 0 | | 1.2 | V |



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